

Multiscale Thermo-Mechanical Modeling

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Imagination at work.







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Transport Phenomena in Engineering Systems are Multiscale Problems



Heat transfer in electrical/electronic systems is a highly coupled, multiscale phenomenon; Need higher fidelity models for improved reliability predictions



Reliability and the 10 °C Rule of Thumb



Probability that a device will operate continuously for a specified time @ stated conditions



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GE SiC Technology for Reliable Operation in Harsh Environments

GE SIC MOSFET



- 1/2 Space & weight, or
- **2x** Power Density
- 2x Reliability
- **>50°C** Higher temperature capability



Distribution

- Leakage Current
- Operating Temperature
 - Radiation Hardness
- On-Resistance
- Blocking Voltage

- Heat Spreading
- Power Density
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How Do Power Electronics Fail?



GE SiC Power Converter Module





- Junction temperature ?
- Stress/strain levels, failures and MTTF?



- 24 die module
- 600 micron gate, 200 °C junction temperature limit
- Wirebond to system ~ 10^3
- 10 layers in chip-ambient thermal stackup
- High switching frequency
- Air cooling with plate-fin heat sink
- Copper busbars, Aluminum wirebonds
- Copper baseplate

Scale Resolved Temperature Predictions



1150 W/m²-K effective heat transfer coefficient;100 micron TIM w/ k = 4.2 W/m-K; 5 mm AI heat sink base; 45 °C ambient





- Thermal shock cycling with 35 W/die power pulse; 10 min. time period; 50% duty cycle; 1 second ramp time
- Unsteady mechanical analysis with data interpolated from ON/OFF thermal data
- Nonlinear material properties for solder (viscoplastic), copper (multilinear kinematic hardening) and Aluminum (bilinear kinematic hardening)
- Coffin-Manson type equation (low cycle fatigue) for estimating MTTF

Failure Analysis: Thermal Shock Cycling



Plastic Strain





368 cycles to thermal shock failure

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Conclusions

- Solder fatigue identified as limiting failure mechanism during thermal shock cycling; >350 cycles to failure
- Multiscale modeling for high fidelity analysis and improved reliability predictions
- Coupled EM ⇔Mechanical ⇔ Thermal analysis needed for simulation driven design and optimization



References

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- Lu, Hua, Chris Bailey, and Chunyan Yin. "Design for reliability of power electronics modules." Microelectronics reliability 49.9 (2009): 1250-1255.



